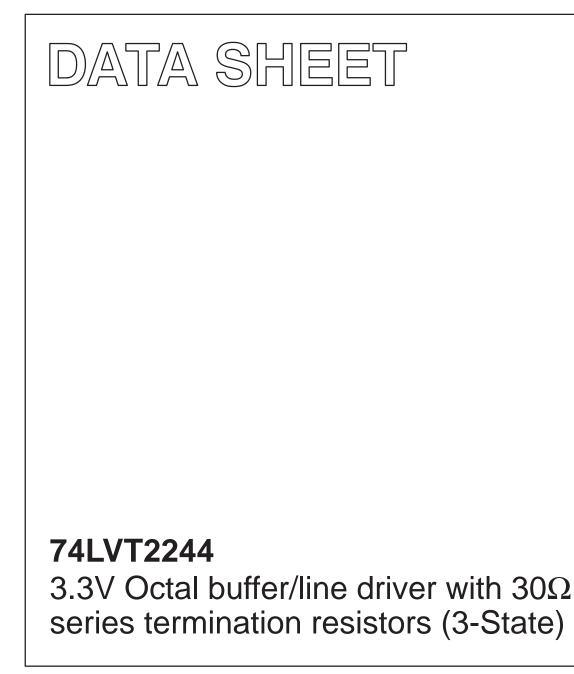
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Aug 28 IC23 Data Handbook

1998 Feb 19



Philips Semiconductors

74LVT2244

FEATURES

- Octal bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up 3-State
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Outputs include series resistance of 30Ω, making external termination resistors unnecessary.

QUICK REFERENCE DATA

DESCRIPTION

The LVT2244 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal buffer that is ideal for driving bus lines. The device features two Output Enables ($\overline{OE1}$, $\overline{OE2}$), each controlling four of the 3-State outputs.

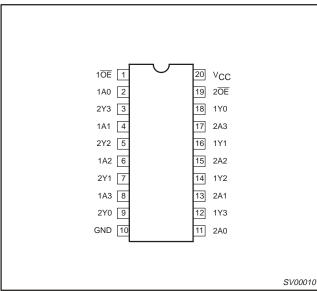
The 74LVT2244 is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces the line noise in applications such as memory address drivers, clock drivers and bus receivers/transmitters.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	2.9 2.9	ns
C _{IN}	Input capacitance	$V_{I} = 0V \text{ or } 3.0V$	4	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_0 = 0V \text{ or } 3.0V$	7	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	0.13	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SOL	-40°C to +85°C	74LVT2244 D	74LVT2244 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +85°C	74LVT2244 DB	74LVT2244 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVT2244 PW	7LVT2244PW DH	SOT360-1

PIN CONFIGURATION

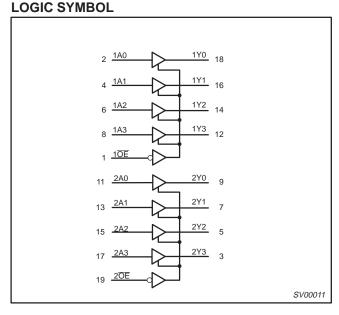


PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
11. 13, 15, 17	2A0 – 2A3	Data inputs
18, 16, 14, 12	1Y0 – 1Y3	Data outputs
9, 7, 5, 3	2Y0 – 2Y3	Data outputs
1, 19	1 <u>0E</u> , 2 <u>0E</u>	Output enables
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

74LVT2244

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

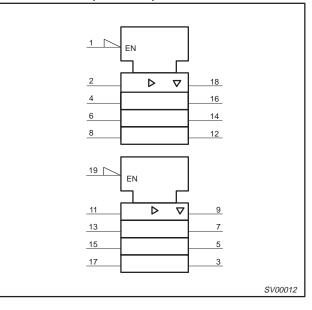
INP	INPUTS				
nOE1	nAx	nYx			
L	L	L			
L	Н	Н			
Н	Х	Z			

H = High voltage level

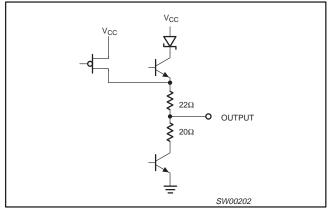
L = Low voltage level

X = Don't care

Z = High impedance "off" state



SCHEMATIC OF EACH OUTPUT



ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
VI	DC input voltage ³		-0.5 to +7.0	V
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
1	DC output current	Output in Low state	128	mA
OUT	De output current	Output in High state	-64	
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
I _{OK}	DC output diode current	V _O < 0	-50	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIDOL	FARAMETER	MIN	MAX	
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
VIL	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-12	mA
I _{OL}	Low-level output current		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate; outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	;	T _{amb} =	= -40°C to	+85°C	UNIT
				MIN	TYP ¹	MAX	1
VIK	Input clamp voltage	$V_{CC} = 2.7V; I_I = -18mA$			0.9	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 3V; I_{OH} = -12mA$		2	2.5		V
V _{OL}	Low-level output voltage	V _{CC} = 3V; I _{OL} = 12mA				0.8	V
		V _{CC} = 0 or 3.6V; V _I = 5.5V			1	10	
h	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$	Control pins		±0.1	±1	μA
η	input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data pins ⁴		0.1	1	μΑ
		$V_{CC} = 3.6V; V_{I} = 0$	Data pins		-1	-5	1
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$	-		1	±100	μΑ
		$V_{CC} = 3V; V_{I} = 0.8V$		75	150		
I _{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_I = 2.0V$		-75	-150		μA
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			1
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 3.0V$			60	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} = \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = 0$ OE/OE = Don't care	GND or V _{CC} ;		±1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V			1	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V$			-1	-5	μΑ
ICCH		V_{CC} = 3.6V; Outputs High, V_{I} = GND o	r V _{CC,} I _{O =} 0		0.12	0.19	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or	V _{CC} , I _{O =} 0		3	12	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GN$	ID or V_{CC} , $I_{O} = 0^5$		0.12	0.19	1
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3.0 to 3.6V; One input at V_{CC} -0 Other inputs at V_{CC} or GND	.6V;		0.1	0.2	mA

NOTES:

All typical values are at T_{amb} = 25°C.
This is the increase in supply current for each input at V_{CC} –0.6V.
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 10% a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND

I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$; $T_{amb} = -40^{\circ}\text{C}$ to +85°C.

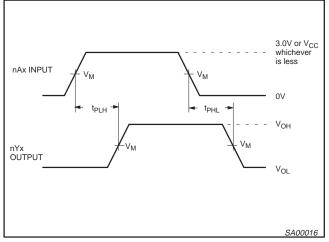
				L	IMITS		
SYMBOL	PARAMETER	WAVEFORM	V _C	_C = 3.3V ±0.3	3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	1
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1 1	2.9 2.9	4.4 4.1	5.3 4.4	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1 1.1	3.7 3.7	5.9 5.5	7.7 6.2	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.9 1.8	4.3 3.3	6.1 4.5	6.8 4.5	ns

NOTE:

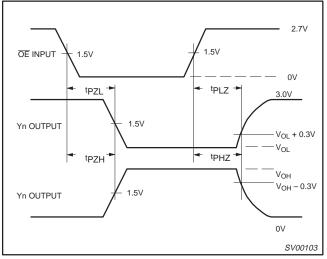
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25^{\circ}C.

AC WAVEFORMS

 V_{M} = 1.5V, V_{IN} = GND to 2.7V

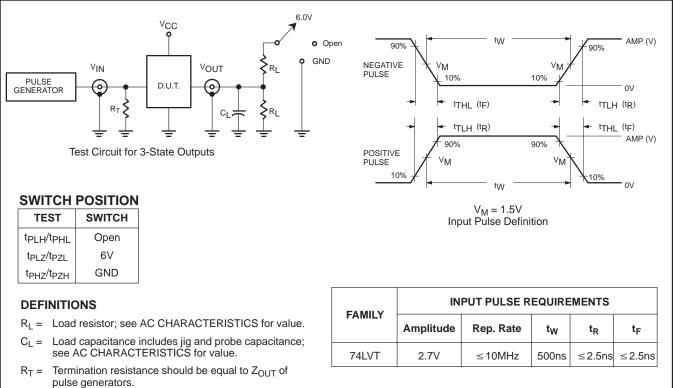


Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



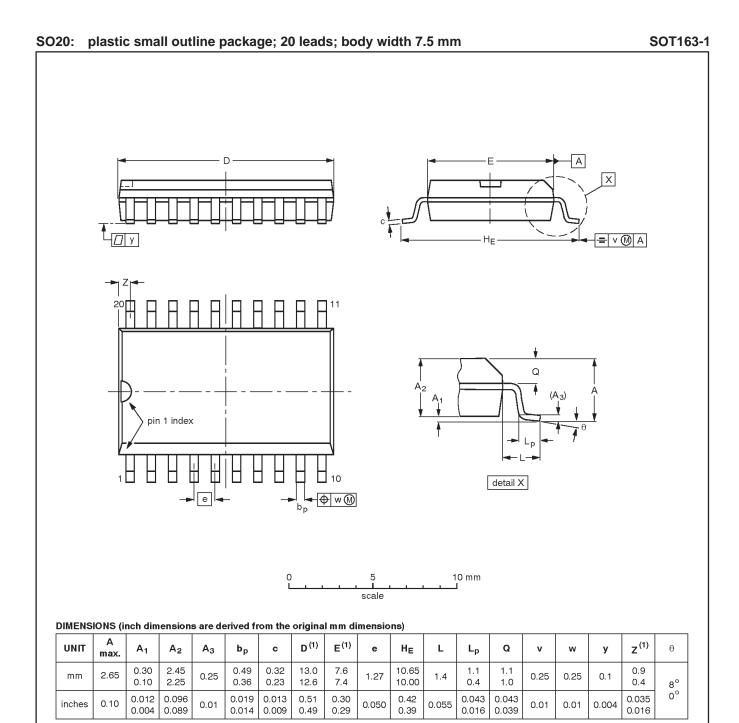
Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



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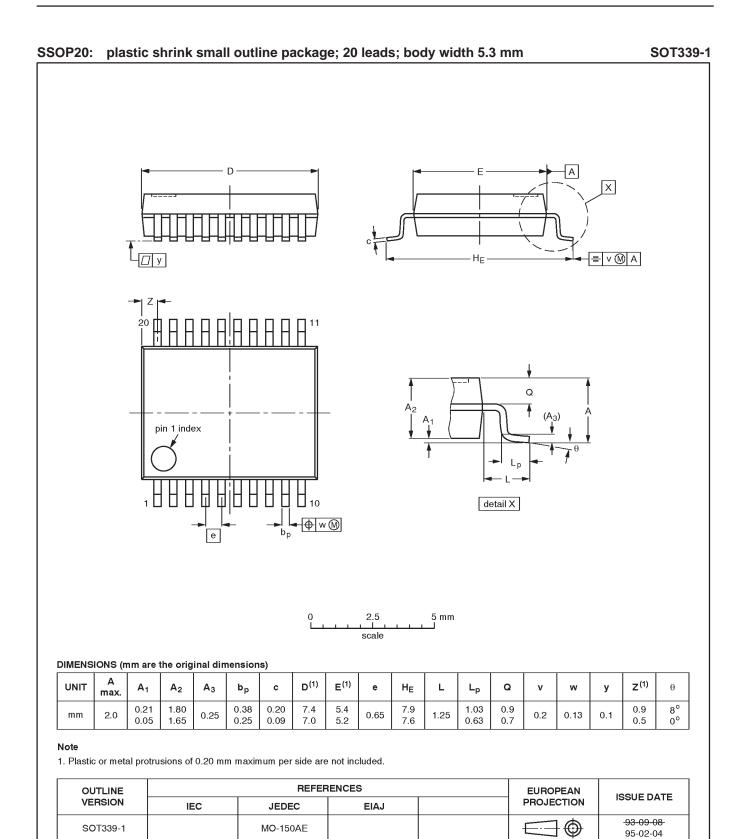


Note

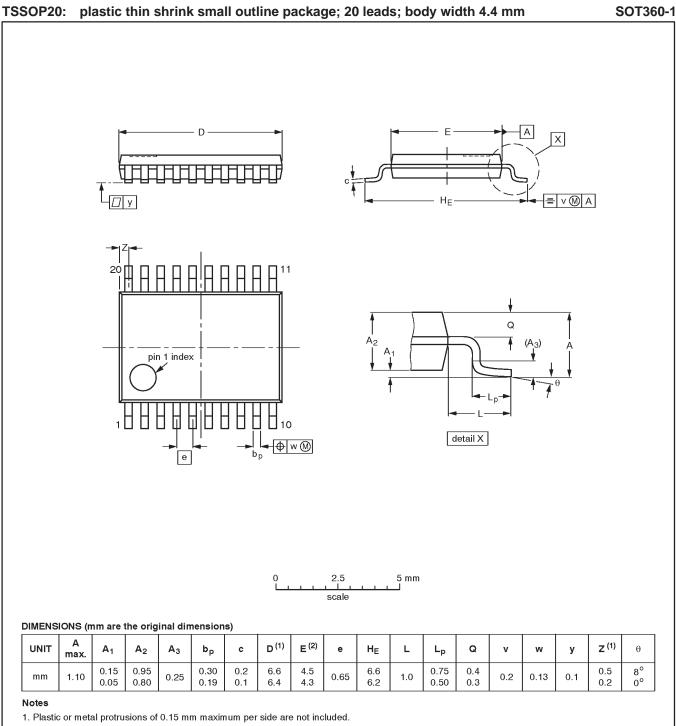
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1350E DATE
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24

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2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENC		REFERENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT360-1		MO-153AC				-93-06-16 95-02-04

Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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